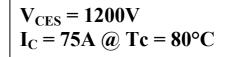
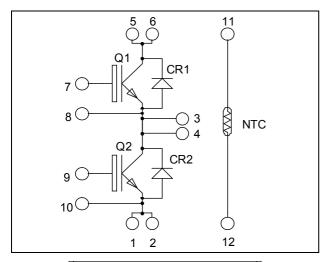
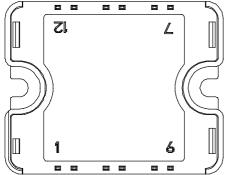


Phase leg Fast Trench + Field Stop IGBT3 Power Module







Pins 1/2; 3/4; 5/6 must be shorted together

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Fast Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Very low stray inductance
 - Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

Absolute maximum ratings

110001400 11441114111 14411150										
Symbol	Parameter		Max ratings	Unit						
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V						
I_{C}	Continuous Collector Current	$T_C = 25^{\circ}C$	110							
	Continuous Conector Current	$T_C = 80$ °C	75	A						
I_{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	175							
V_{GE}	Gate – Emitter Voltage		±20	V						
P_{D}	Maximum Power Dissipation	$T_C = 25^{\circ}C$	357	W						
RBSOA	Reverse Bias Safe Operating Area	$T_{j} = 125^{\circ}C$	150A @ 1150V							

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				250	μΑ
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.4	1.7	2.1	V
V CE(sat)	Conector Emitter Saturation Voltage	$I_C = 75A$	$T_{j} = 125^{\circ}C$		2.0		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 3 \text{ mA}$		5.0		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V$			5340		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			280		pF
C_{res}	Reverse Transfer Capacitance	f = 1MHz		240			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	ning (25°C)		260		
T_{r}	Rise Time	$V_{GE} = \pm 15V$			30		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 75A$			420		ns
T_{f}	Fall Time	$R_G = 4.7\Omega$		70		1	
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_C = 75A$			285		
T_{r}	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				520		ns
$T_{\rm f}$	Fall Time	$R_G = 4.7\Omega$			90		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		7	·	I en
E_{off}	Turn-off Switching Energy	$I_C = 75A$ $R_G = 4.7\Omega$	$T_j = 125$ °C		8.1		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25$ °C			350	μA
1 _{RM}	Waximum Reverse Leakage Current	V _R -1200 V	$T_{j} = 125^{\circ}C$			600	μΑ
I_F	DC Forward Current		$Tc = 80^{\circ}C$		75		A
$V_{\rm F}$	Diode Forward Voltage	$I_F = 75A$	$T_i = 25$ °C		1.6	2.1	V
* F	Blode Forward Voluge		$T_j = 125$ °C		1.6		<u> </u>
t _{rr}	Reverse Recovery Time		$T_j = 25^{\circ}C$		170		ns
٠rr	Reverse Recovery Time		$T_{j} = 125^{\circ}C$		280		113
0	Reverse Recovery Charge	$I_F = 75A$ $V_R = 600V$ $di/dt = 2000A/\mu s$	$T_j = 25^{\circ}C$		7		μС
Q_{rr}	Reverse Recovery Charge			$T_{j} = 125^{\circ}C$		14	
Е	E _r Reverse Recovery Energy	•	$T_j = 25$ °C		2.8		mJ
\mathbf{E}_{r}		$T_i = 125^{\circ}C$		5.4		1113	



Thermal and package characteristics

Symbol	Characteristic					Тур	Max	Unit
D	lunction to Case Thermal Resistance		IG	BT			0.35	°C/W
R_{thJC}			ode			0.58	C/W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz				4000			V
T_{J}	Operating junction temperature range			-40		150		
T_{STG}	Storage Temperature Range			-40		125	°C	
T_{C}	Operating Case Temperature						100	
Torque	Mounting torque	To heatsink	[M4	2		3	N.m
Wt	Package Weight		•				80	g

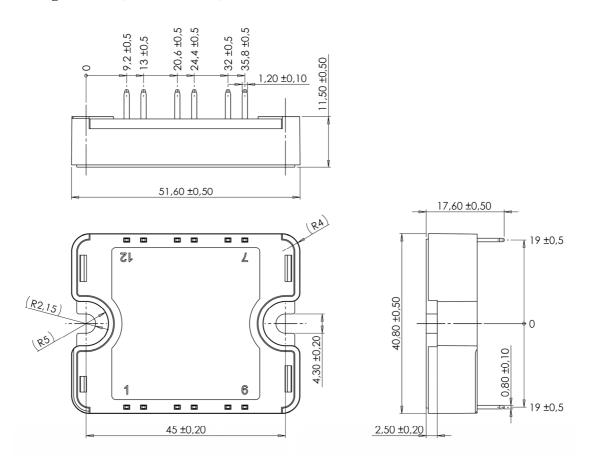
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B _{25/85}	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_{T}: \text{Thermistor value at T}$$

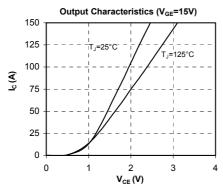
SP1 Package outline (dimensions in mm)

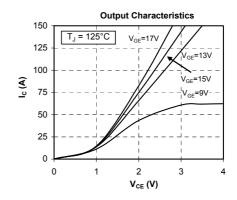


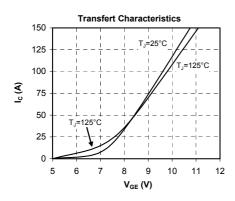
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

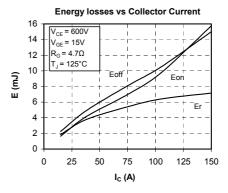


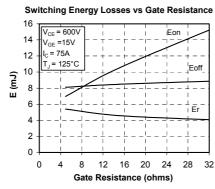
Typical Performance Curve

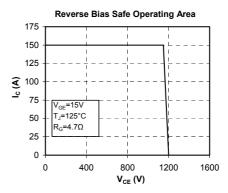


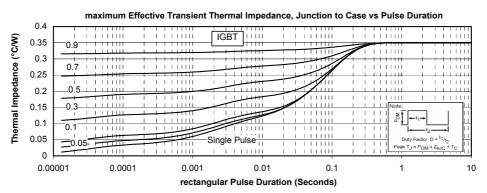




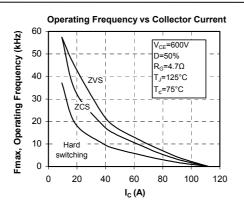


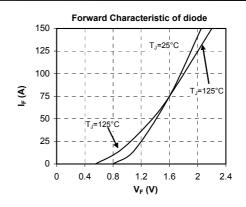


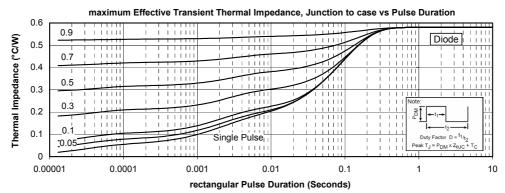












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